

# 1S2076

Silicon Epitaxial Planar Diode for Various Detector,  
Modulator, Demodulator

# HITACHI

ADE-208-145A (Z)  
Rev. 1  
Aug. 1995

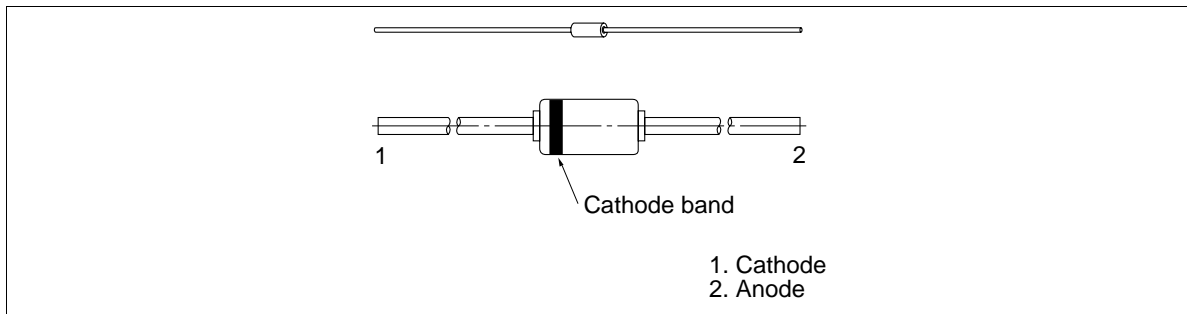
## Features

- Low capacitance. ( $C = 3.0\text{pF max}$ )
- Short reverse recovery time. ( $t_r = 8.0\text{ns max}$ )
- High reliability with glass seal.

## Ordering Information

Type No.	Cathode band	Package Code
1S2076	Light Blue	DO-35

## Outline



## Absolute Maximum Ratings (Ta = 25°C)

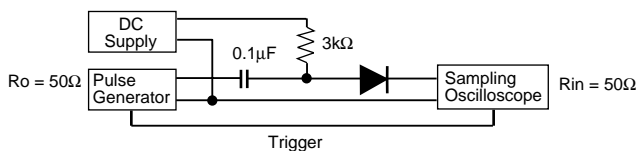
Item	Symbol	Value	Unit
Peak reverse voltage	$V_{RM}$	35	V
Reverse voltage	$V_R$	30	V
Peak forward current	$I_{FM}$	450	mA
Non-Repetitive peak forward surge current	$I_{FSM}^*$	1	A
Average forward current	$I_O$	150	mA
Power dissipation	Pd	250	mW
Junction temperature	Tj	175	°C
Storage temperature	Tstg	-65 to +175	°C

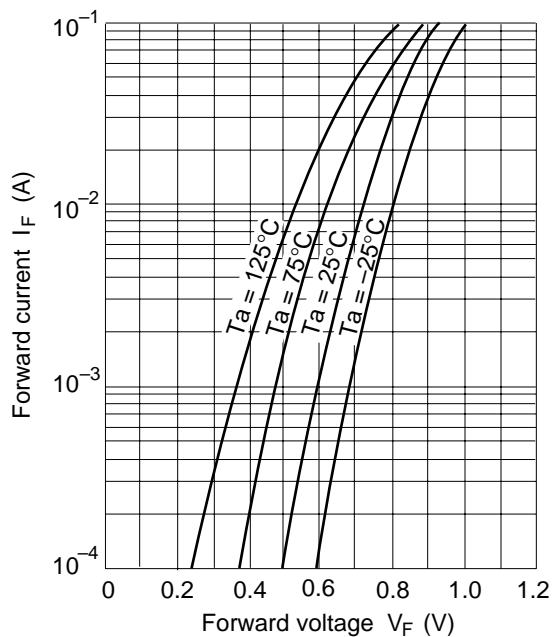
Note: Within 1s forward surge current.

## Electrical Characteristics (Ta = 25°C)

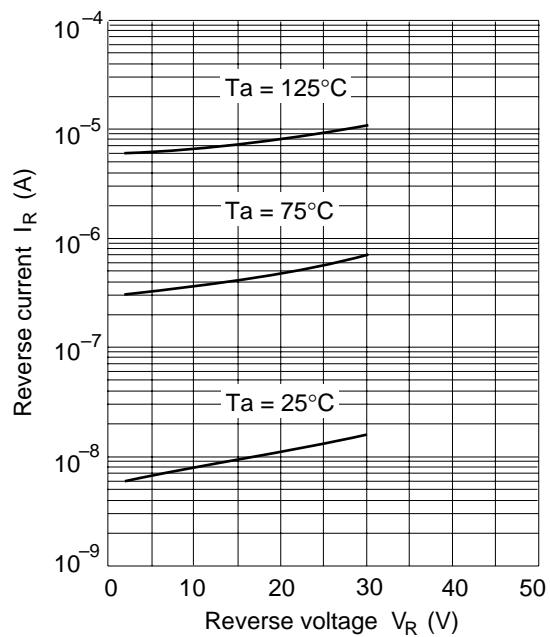
Item	Symbol	Min	Typ	Max	Unit	Test Condition
Forward voltage	$V_F$	0.64	—	0.80	V	$I_F = 10\text{mA}$
Reverse current	$I_R$	—	—	0.1	$\mu\text{A}$	$V_R = 30\text{V}$
Capacitance	C	—	—	3.0	pF	$V_R = 1\text{V}, f = 1\text{MHz}$
Reverse recovery time	$t_{rr}^*$	—	—	8.0	ns	$I_F = I_R = 10\text{mA}, I_{rr} = 1\text{mA}$

Note: Reverse recovery time test circuit





**Fig.1 Forward current Vs. Forward voltage**



**Fig.2 Reverse current Vs. Reverse voltage**

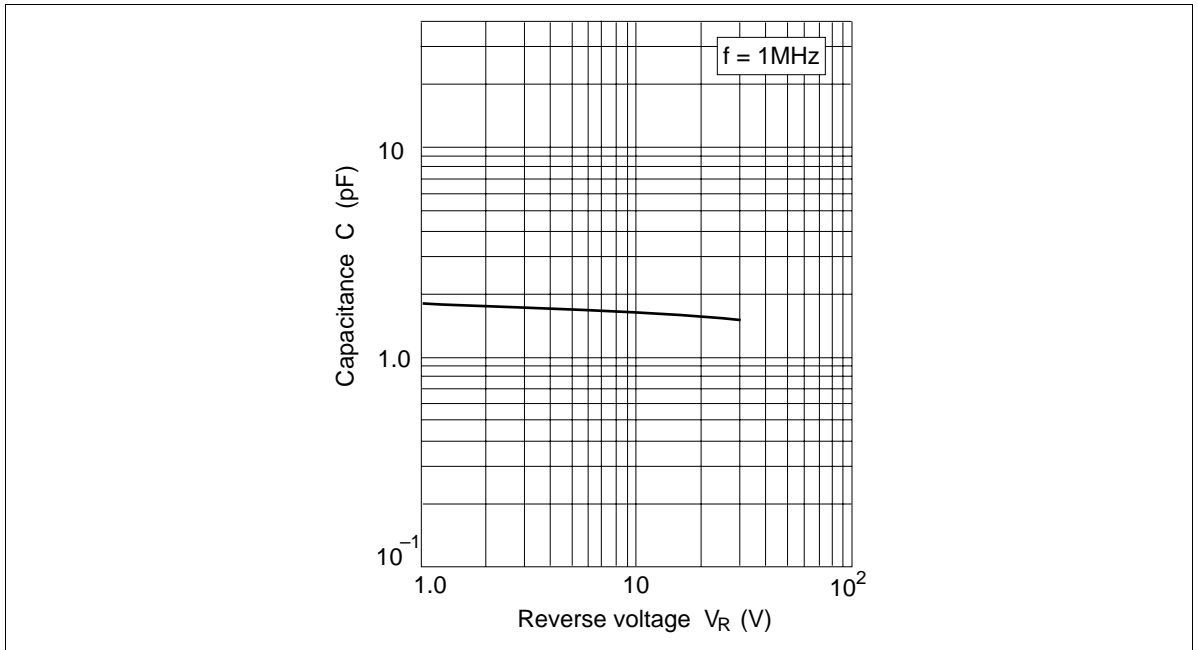
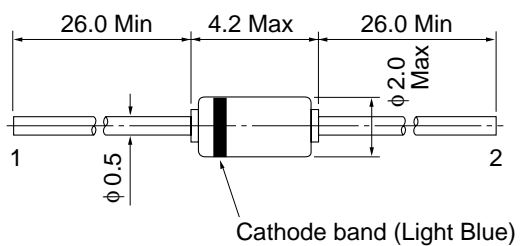


Fig.3 Capacitance Vs. Reverse voltage

## Package Dimensions

Unit: mm



1 Cathode  
2 Anode

HITACHI Code	DO-35
JEDEC Code	DO-35
EIAJ Code	SC-48
Weight (g)	0.13

## Cautions

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